DSC2011FI1-E0012



Crystal-lessTM Configurable Clock Generator

General Description

The DSC2011FI1-E0012 is a programmable, high performance dual LVCMOS output oscillator utilizing Micrel's proven silicon MEMS technology to provide excellent jitter and stability while incorporating additional device functionality. Two LVCMOS outputs are controlled by separate supply voltages to allow for independent voltage level control. The frequencies of the outrputs can be identical or independently derived from a common PLL frequency source.

The DSC2011FI1-E0012 has provision for up to eight user-defined pre-programmed, pin-selectable output frequency combinations. The DSC2011FI1-E0012 is also equipped with independent pin-selectable output drive strengths to reduce EMI and noise.

Applications

- Consumer Electronics
- Storage Area Networks
 - SATA, SAS, Fibre Channel
- Passive Optical Networks
 - EPON, 10G-EPON, GPON, 10G-GPON
- Ethernet
- 1G, 10GBASE-T/KR/LR/SR, and FCoE
- HD/SD/SDI Video & Surveillance
- PCI Express
- Automotive

Features

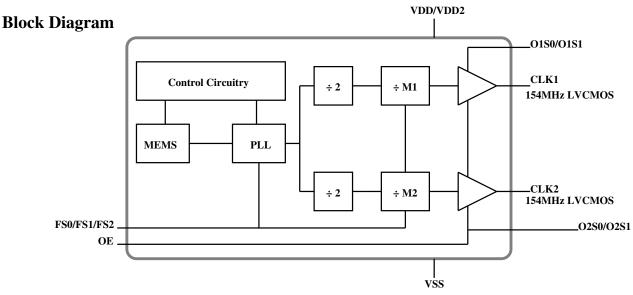
- Frequency and output formats:
 - LVCMOS

154/65/71/108/119/130.25/148.5/162MHz

- LVCMOS

154/65/71/108/119/130.25/148.5/162MHz

- Low RMS phase jitter: <1ps (typ)
- ±50ppm frequency stability
- -40°C to +85°C industrial temperature range
- High supply noise rejection: -50dBc
- Pin-selectable configurations
 - 2-bit output drive strength
 - Up to 8 output frequency combinations
- Excellent shock & vibration immunity
 - Qualified to MIL-STD-883
- High reliability
 - 20x better MTF than quartz oscillators
- Supply range of 2.25 to 3.6V
- AEC-Q100 automotive qualified
- 14-pin 3.2mm x 2.5mm QFN package



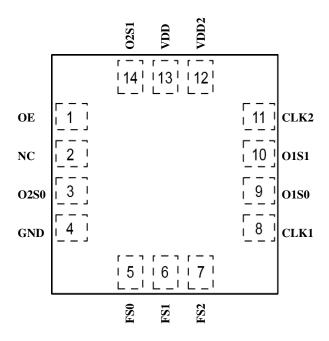
 $Micrel\ Inc. \bullet 2180\ Fortune\ Drive \bullet San\ Jose,\ CA\ 95131 \bullet USA \bullet tel\ +1\ (408)\ 944-0800 \bullet fax\ +\ 1\ (408)\ 474-1000 \bullet \ http://www.micrel.com$

Ordering Information

Ordering Part Number	Industrial Temperature Range	Shipping	Package	
DSC2011FI1-E0012	-40°C to +85°C	Tube	14-pin 3.2mm x 2.5mm QFN	
DSC2011FI1-E0012T	C2011FI1-E0012T -40°C to +85°C		14-pin 3.2mm x 2.5mm QFN	

Devices are Green and RoHS compliant. Sample material may have only a partial top mark.

Pin Configuration



14-pin 3.2mm x 2.5mm QFN

Pin Description

Pin Number	Pin Name	Pin Type	Pin Function	
1	OE	I	Enables outputs when high and disables outputs when low	
2	NC		Leave unconnected or connect to ground	
3	O2S0	I	Least significant bit for drive strength selection for CLK2, see Table 1 for details	
4	GND	PWR	Ground	
5	FS0	I	Least significant bit for frequency selection, see Table 2 for details	
6	FS1	I	Middle bit for frequency selection, see Table 2 for details	
7	FS2	I	Most significant bit for frequency selection, see Table 2 for details	
8	CLK1	О	LVCMOS output	
9	O1S0	I	Least significant bit for drive strength selection for CLK1, see Table 1 for details	
10	O1S1	I	Most significant bit for drive strength selection for CLK1, see Table 1 for details	
11	CLK2	О	LVCMOS output	
12	VDD2	PWR	Power supply for LVCMOS output CLK2	
13	VDD	PWR	Power supply	
14	O2S1	I	Most significant bit for drive strength selection for CLK2, see Table 1 for details	

Operational Description

The DSC2011FI1-E0012 is a dual output LVCMOS oscillator consisting of a MEMS resonator and a supporting PLL IC. The two LVCMOS outputs are generated through independent 8-bit programmable dividers from the output of the internal PLL. The two constraints are imposed on the output frequencies:

1) f2 = M x f1/N, where M and N are even integers between 4 and 254, 2) 1.2GHz < N x f2 < 1.7GHz.

The actual frequencies output by DSC2011FI1-E0012 are controlled by an internal pre-programmed memory (OTP). This memory stores all coefficients required by the PLL for up to eight different frequency combinations. Three control pins (FS0 - FS2) select the output frequency combination.

DSC2011FI1-E0012 has independent control of the output voltage levels of the two outputs. The high voltage level of

CLK1 is equal to the main supply voltage, VDD (pin 13). VDD2 (pin 12) sets the high voltage level of CLK2. VDD2 must be equal to or less than VDD at all times to insure proper operation. VDD2 can be as low as 1.65V. When OE (pin 1) is floated or connected to VDD, the DSC2011FI1-E0012 is in operational mode. Driving Enable to ground will tri-state both output drivers (hi-impedance mode).

DSC2011FI1-E0012 has programmable output drive strength for each output. Using two control pins (OXS0-OXS1) for each output, the drive strength can be independently adjusted to match circuit board impedances to reduce spower supply noise, overshoot/undershoot and EMI. Table 1 displays typical rise / fall times for the output with a 15pF load capacitance as a function of these control pins at VDD = 3.3V and room temperature.

	Output Drive Strength Bits [OXS1, OXS0] - Default is [11]				
	00	01	10	11	
tr (ns)	1.6	1.4	1.2	1.1	
tf (ns)	2.4	2.2	1.5	1.4	

Table 1. Rise/Fall Times for Drive Strengths

Output Clock Frequencies

Frequency select bits are weakly tied high so if left unconnected the default setting will be [111] and the device will output the associated frequency highlighted in bold.

Eroc (MHz)	Freq Select Bits [FS2, FS1, FS0] - Default is [111]							
Freq (MHz)	000	001	010	011	100	101	110	111
CLK1	65	71	108	119	130.25	148.5	162	154
CLK2	65	71	108	119	130.25	148.5	162	154

Table 2. Pin-Selectable Output Frequencies

Absolute Maximum Ratings

Item	Min.	Max.	Units	Condition
Supply Voltage	-0.3	+4.0	V	
Input Voltage	-0.3	VDD + 0.3	V	
Junction Temp	-	+150	°C	
Storage Temp	-55	+150	°C	
Soldering Temp	-	+260	°C	40sec max.
ESD HBM MM CDM	-	4000 400 1500	V	

1000+ years of data retention on internal memory

Specifications (Unless specified otherwise: T = 25°C, max LVCMOS drive strength)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Units
Supply Voltage ¹	Supply Voltage ¹ VDD		2.25		3.6	V
Supply Current	IDD	OE pin low - outputs are disabled		21	23	mA
Supply Current ²	Supply Current ² IDD OE pin high - outputs are enabled $CL = 15pF$, $F01 = F02 = 125MHz$			32		mA
Frequency Stability	ΔF	Includes frequency variation due to initial tolerance, temp. and power supply voltage			±50	ppm
Aging	ΔF	First year (@ 25°C)			±5	ppm
Startup Time ³	tSU	T = 25°C			5	ms
Input Logic Levels Input Logic High Input Logic Low	VIH VIL		0.75 x VDD		0.25 x VDD	V
Output Disable Time ⁴	tDA				5	ns
Output Enable Time	tEN				20	ns
Pull-Up Resistor ²		Pull-up exists on all digital IO		40		kOhms
		LVCMOS Outputs				
Output Logic Levels Output Logic High Output Logic Low	VOH VOL	I = ±6mA	0.9 x VDD		- 0.1 x VDD	V
Output Transition Time ⁴ Rise Time Fall Time	tR tF	20% to 80% CL = 15pF		1.1 1.4	2 2	ns
Frequency	CLK1 CLK2	[FS2, FS1, FS0] = [1, 1, 1]		154 154		MHz
Output Duty Cycle	SYM		45		55	%
Period Jitter ⁵	JPER	F01 = F02 = 125MHz		3		psRMS
Integrated Phase Noise	JPH	200kHz to 20MHz @ 125MHz 100kHz to 20MHz @ 125MHz 12kHz to 20MHz @ 125MHz		0.3 0.38 1.7	2	psRMS

Notes:

- 1. Pin 12 VDD2, and pin 13 VDD should be filtered with $0.1 uF\ capacitors.$
- 2. Output is enabled if OE pin is floated or not connected.
- 3. tSU is time to 100ppm stable output frequency after VDD is applied and outputs are enabled.
- 4. Output Waveform and Test Circuit figures below define the parameters.
- 5. Period Jitter includes crosstalk from adjacent output.

Nominal Performance Parameters (Unless specified otherwise: T = 25°C, VDD = 3.3V)

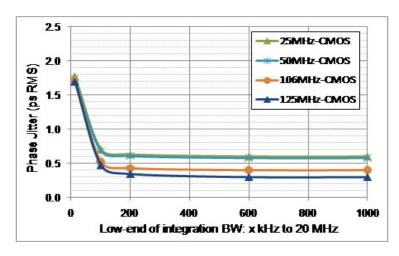


Figure 1. LVCMOS Phase Jitter (integrated phase noise)

LVCMOS Output Waveform

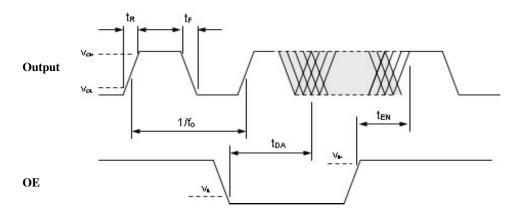


Figure 2. LVCMOS Output Waveform

MSL 1 @ 260°C refer to JSTD-020C				
Ramp-Up Rate (200°C to Peak Temp)	3°C/sec Max.			
Preheat Time 150°C to 200°C	60 - 180 sec			
Time maintained above 217°C	60 - 150 sec			
Peak Temperature	255 - 260°C			
Time within 5°C of actual Peak	20 - 40 sec			
Ramp-Down Rate	6°C/sec Max.			
Time 25°C to Peak Temperature	8 min Max.			

Solder Reflow Profile

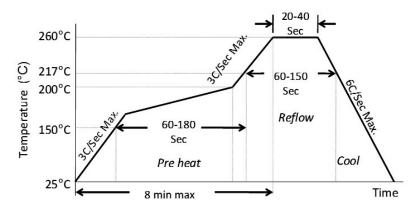
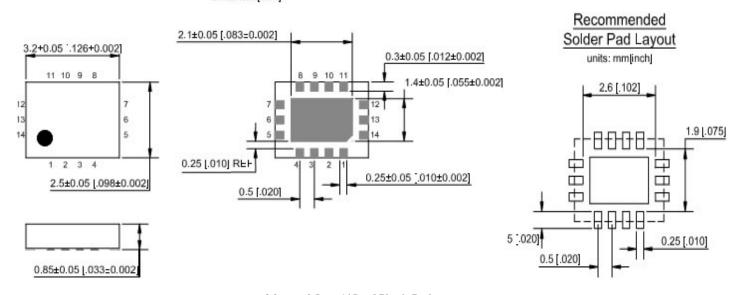


Figure 3. Solder Reflow Profile

Package Information⁷

External Dimensions units: mm[inch]



Notes:

3.2mm x 2.5mm 14 Lead Plastic Package

- 6. Connect the exposed die paddle to ground.
- 7. Package information is correct as of the publication date. For updates and most current information, go to www.micrel.com.

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